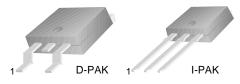


MJD47/50

High Voltage and High Reliability D-PAK for Surface Mount Applications

- Load Formed for Surface Mount Application (No Suffix)
- Straight Lead (I-PAK, "- I" Suffix)
- Electrically Similar to Popular TIP47 and TIP50



1.Base 2.Collector 3.Emitter

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Emitter Voltage		
	: MJD47	350	V
	: MJD50	500	V
V _{CEO}	Collector-Emitter Voltage		
	: MJD47	250	V
	: MJD50	400	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current (DC)	1	Α
I _{CP}	Collector Current (Pulse)	2	Α
I _B	Base Current	0.6	Α
P _C	Collector Dissipation (T _C =25°C)	15	W
	Collector Dissipation (T _a =25°C)	1.56	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 65 ~ 150	°C

Electrical Characteristics $T_C=25$ °C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
V _{CEO} (sus)	* Collector-Emitter Sustaining Voltage				
	: MJD47	$I_C = 30 \text{mA}, I_B = 0$	250		V
	: MJD50		400		V
I _{CEO}	Collector Cut-off Current				
	: MJD47	$V_{CE} = 150V, I_{B} = 0$		0.2	mA
	: MJD50	$V_{CE} = 300V, I_B = 0$		0.2	mA
I _{CES}	Collector Cut-off Current				
	: MJD47	$V_{CE} = 350, V_{EB} = 0$		0.1	mA
	: MJD50	$V_{CE} = 500, V_{EB} = 0$		0.1	mA
I _{EBO}	Emitter Cut-off Current	$V_{BE} = 5V, I_{C} = 0$		1	mA
h _{FE}	* DC Current Gain	$V_{CE} = 10V, I_{C} = 0.3A$	30	150	
		$V_{CE} = 10V, I_{C} = 1A$	10		
V _{CE} (sat)	* Collector-Emitter Saturation Voltage	$I_C = 1A, I_B = 0.2A$		1	V
V _{BE} (sat)	* Base-Emitter Saturation Voltage	V _{CE} = 10A, I _C = 1A		1.5	V
f _T	Current Gain Bandwidth Product	V _{CE} =10V, I _C = 0.2A	10		MHz

* Pulse Test: PW≤300μs, Duty Cycle≤2%

Typical Characteristics

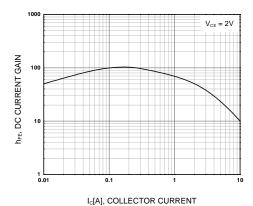


Figure 1. DC current Gain

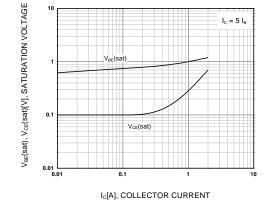


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

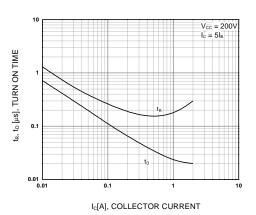


Figure 3. Turn On Time

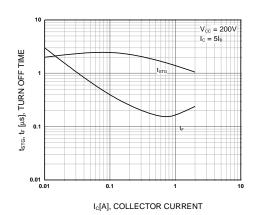


Figure 4. Turn Off Time

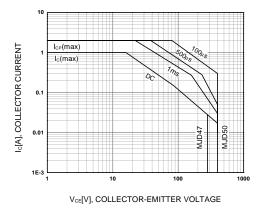


Figure 5. Safe Operating Area

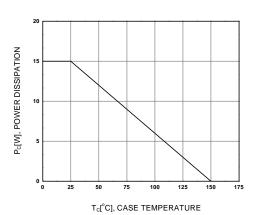
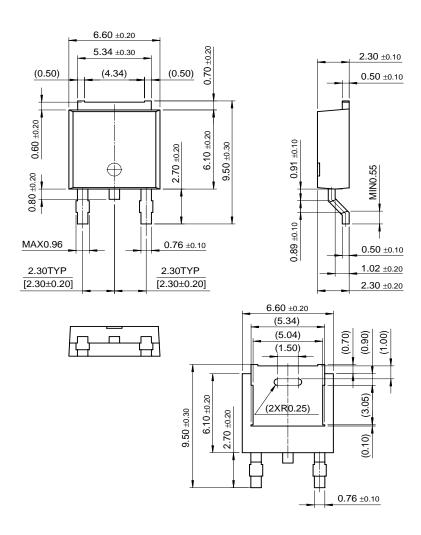


Figure 6. Power Derating

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Package Demensions

D-PAK



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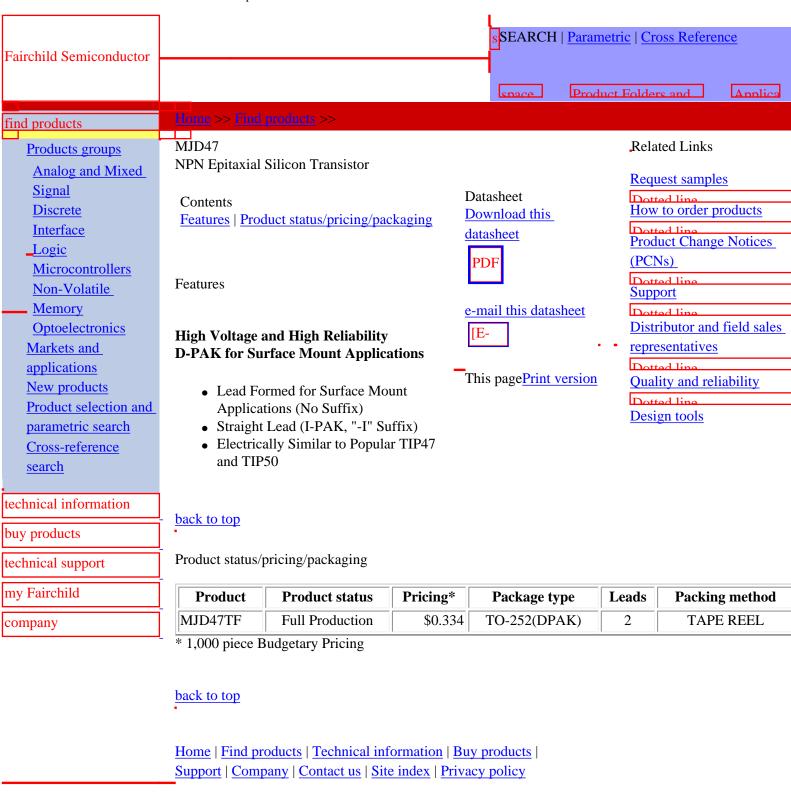
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